GSDSS12FL Series

Surface Mount Glass Passivated Silicon Rectifier

Product Description

Reverse Voltage 20 to 200V Forward Current 1.0A

Features

- Low profile package
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability

Mechanical Data

- Case : Molded plastic, SOD-123FL
- Terminals : Solder plated, solderable per MIL-STD-750, method 2026 guaranteed
- Polarity : Color band denotes cathode end

Package

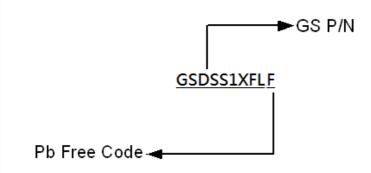


SOD-123FL



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Ordering Information



Part Number	Package	Quantity
GSDSS12FLF	SOD-123FL	3,000 PCS
GSDSS13FLF	SOD-123FL	3,000 PCS
GSDSS14FLF	SOD-123FL	3,000 PCS
GSDSS16FLF	SOD-123FL	3,000 PCS
GSDSS18FLF	SOD-123FL	3,000 PCS
GSDSS110FLF	SOD-123FL	3,000 PCS
GSDSS115FLF	SOD-123FL	3,000 PCS
GSDSS120FLF	SOD-123FL	3,000 PCS

Marking Information

P/N	Part Marking	Package
GSDSS12FLF	K12	SOD-123FL
GSDSS13FLF	K13	SOD-123FL
GSDSS14FLF	K14	SOD-123FL
GSDSS16FLF	K16	SOD-123FL
GSDSS18FLF	K18	SOD-123FL
GSDSS110FLF	K110	SOD-123FL
GSDSS115FLF	K115	SOD-123FL
GSDSS120FLF	K120	SOD-123FL





Electrical Characteristics

Ratings at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60HZ, resistive or inductive load. For capacitive load, derate current by 20%.

Conditions	Symbols	GSDSS12FLF	GSDSS13FLF	Units
Maximum Recerrent Peak Reverse Voltage	VRRM	20	30	Volts
Maximum RMS Voltage	V _{RMS}	14	21	Volts
Maximum DC Blocking Voltage	V _{DC}	20	30	Volts
Maximum Forward Voltage at 1.0A(Note 1)	VF	0.55		Volts
Conditions	Symbols	GSDSS14FLF	GSDSS16FLF	Units
Maximum Recerrent Peak Reverse Voltage	V _{RRM}	40	60	Volts
Maximum RMS Voltage	V _{RMS}	28	42	Volts
Maximum DC Blocking Voltage	V _{DC}	40	60	Volts
Maximum Forward Voltage at 1.0A(Note 1)	VF	0.55	0.75	Volts
Conditions	Symbols	GSDSS18FLF	GSDSS110FLF	Units
Maximum Recerrent Peak Reverse Voltage	VRRM	80	100	Volts
Maximum RMS Voltage	V _{RMS}	56	70	Volts
Maximum DC Blocking Voltage	V _{DC}	80	100	Volts
Maximum Forward Voltage at 1.0A(Note 1)	VF	0.85		Volts
Conditions	Symbols	GSDSS115FLF	GSDSS120FLF	Units
Maximum Recerrent Peak Reverse Voltage	V _{RRM}	150	200	Volts
Maximum RMS Voltage	V _{RMS}	105	140	Volts
Maximum DC Blocking Voltage	V _{DC}	150	200	Volts
Maximum Forward Voltage at 1.0A(Note 1)	VF	0.95		Volts
Maximum Average Forward Rectified Current @TA=50°C	I(AV)	1.0		Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	IFSM	25.0		Amp
Maximum Reverse Current at at TA=25℃ at Rated DC Blocking Voltage TA=100℃	I _R	1.0 20		mAmp
Typical Junction Capacitance (Note 1)	CJ	8	3	pF
Typical Thermal Resistance (Note 2)	Reja	88.0		°C/W
Operating and Storage Temperature Range	TJ	-50 to +125		°C
Storage Temperature Range	Tstg	-50 to +125		°C

NOTES:

1- Pulse test: 300μs pulse width, 1% duty cycle 2- Mounted on FR-4 P.C.B. With 0.9x1.5 mm copper pad areas (≈35 μm thick)



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Typical Characteristics

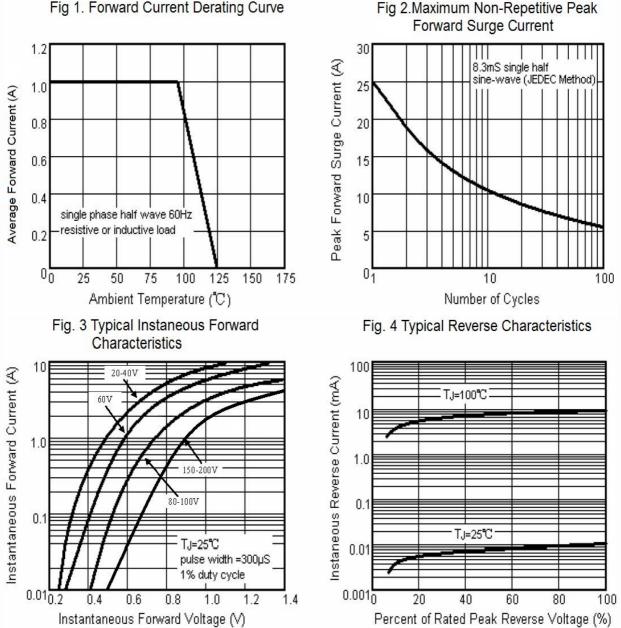
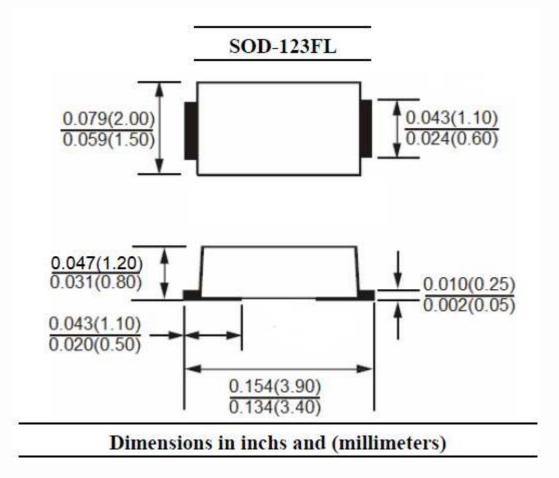


Fig 1. Forward Current Derating Curve



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Package Dimension





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